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VS-MBR1100, VS-MBR1100-M3

Vishay Semiconductors

N Cathode Anode

PRODUCT SUMMARY					
Package	DO-204AL (DO-41)				
I _{F(AV)}	1 A				
V _R	100 V				
V _F at I _F	0.68 V				
I _{RM} max.	1.0 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	1.0 mJ				

Schottky Rectifier, 1 A

FEATURES

- · Low profile, axial leaded outline
- · Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



COMPLIANT

HALOGEN FREE

Available

- · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

DESCRIPTION

The VS-MBR1100... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	1.0	A				
V _{RRM}		100	V				
I _{FSM}	t _p = 5 μs sine	200	А				
V _F	1 Apk, T _J = 125 °C	0.68	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBR1100	VS-MBR1100-M3	UNITS
Maximum DC reverse voltage	V _R	100	100	M
Maximum working peak reverse voltage	V _{RWM}	100	100	v

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS		
Maximum average forward current See fig. 4	I _{F(AV)}	$I_{F(AV)}$ 50 % duty cycle at T _C = 85 °C, rectangular waveform		10			
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse Following any rated load condition and with rated	200	А			
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	50			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by, T _J maximum V _A = 1.5 x V _R typical		0.5	А		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V _{FM} ⁽¹⁾	1 A	T. = 25 °C	0.85	V	
Maximum forward voltage drop See fig. 1		2 A	1j=25 C	0.96		
		1 A	T 105 %C	0.68		
		2 A	T _J = 125 °C	0.78		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{B} = Rated V_{B}$	0.5		
See fig. 2	'RM \''	T _J = 125 °C	$v_{\rm R}$ = naleu $v_{\rm R}$	1.0	IIIA	
Typical junction capacitance	C _T	V_{R} = 5 V_{DC} , (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\mathrm{C}$		35	pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000			V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

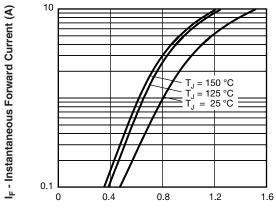
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	80	°C/W		
Approvimete weight			0.33	g		
Approximate weight			0.012	oz.		
Marking device		Case style DO-204AL (DO-41) (JEDEC)	MBR	1100		

Notes

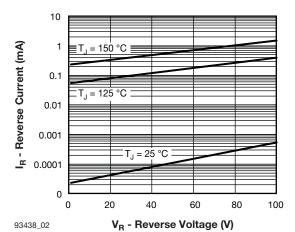
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

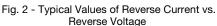
⁽²⁾ Mounted 1" square PCB, thermal probe connected to lead 2 mm from package

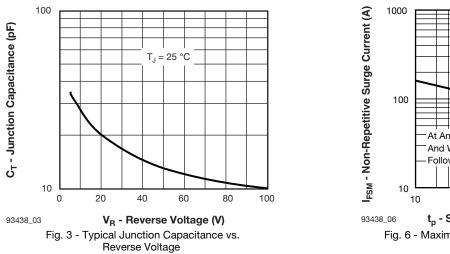




V_{FM} - Forward Voltage Drop (V) 93438 01 Fig. 1 - Maximum Forward Voltage Drop Characteristics

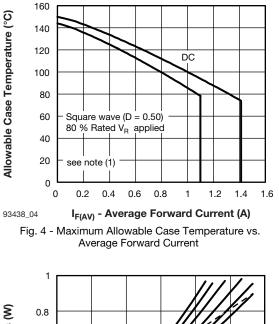


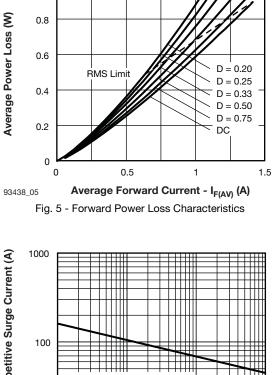


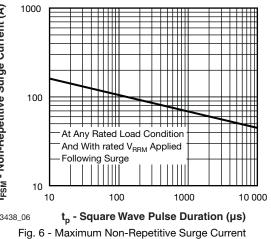


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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

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Device code	VS	- MBR	1	100	TR	-M3
) (2)	3	4	5	6
	1 2 3 4 5	 School Curr Volta TR = 	ottky ME ent ratii age ratii Tape a	iconduct 3R serie ng: 1 = ⁻ ng: 100 and reel c packag	es 1 A = 100 ^v packag	V
	6	• No		tal digit ad (Pb)- ogen-free		

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-MBR1100	1000	1000	Bulk			
VS-MBR1100TR	5000	5000	Tape and reel			
VS-MBR1100-M3	1000	1000	Bulk			
VS-MBR1100TR-M3	5000	5000	Tape and reel			

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95241</u>						
Part marking information	www.vishay.com/doc?95304					
Packaging information	www.vishay.com/doc?95338					

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27.0 (1.06) MIN. (2 places)

1.27 (0.050) MAX.

Flash (2 places)

2.70 (0.106)

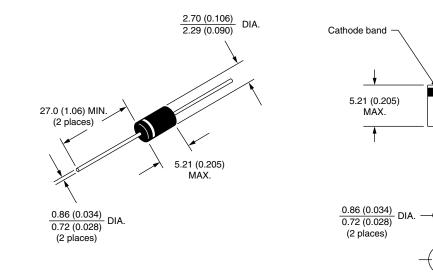
2.29 (0.090)

DIA.



Axial DO-204AL (DO-41)

DIMENSIONS in millimeters (inches)



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